

### TRIPLE 3 - INPUT AND GATE

The TC74AC11 is an advanced high speed CMOS 3-INPUT AND GATE fabricated with silicon gate and double - layer metal wiring C<sup>2</sup>MOS technology.

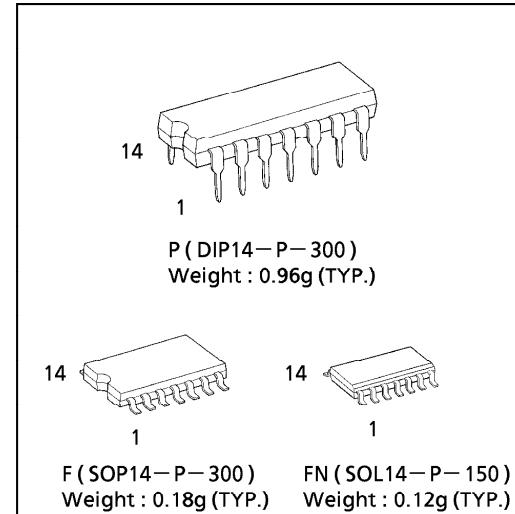
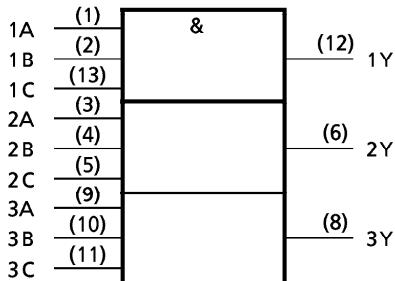
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

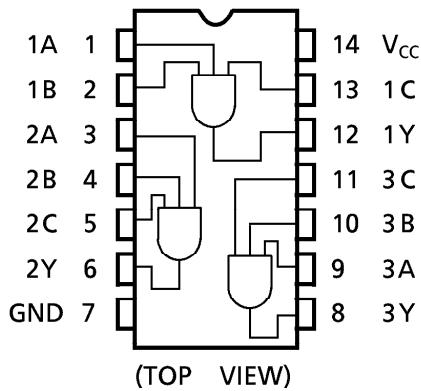
#### FEATURES :

- High Speed..... $t_{pd} = 5.3\text{ns}$  (typ.) at  $V_{CC} = 5\text{V}$
- Low Power Dissipation..... $I_{CC} = 4\mu\text{A}$ (Max.) at  $T_a = 25^\circ\text{C}$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (Min.)
- Symmetrical Output Impedance..... $|I_{OH}| = |I_{OL}| = 24\text{mA}$  (Min.)  
Capability of driving  $50\Omega$  transmission lines.
- Balanced Propagation Delays..... $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range..... $V_{CC}$  (opr) =  $2\text{V} \sim 5.5\text{V}$
- Pin and Function Compatible with 74F11

#### IEC LOGIC SYMBOL



#### PIN ASSIGNMENT



#### TRUTH TABLE

A	B	C	Y
L	X	X	L
X	L	X	L
X	X	L	L
H	H	H	H

X : Don't Care

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	$V_{CC}$	-0.5~7.0	V
DC Input Voltage	$V_{IN}$	-0.5~ $V_{CC}$ + 0.5	V
DC Output Voltage	$V_{OUT}$	-0.5~ $V_{CC}$ + 0.5	V
Input Diode Current	$I_{IK}$	$\pm 20$	mA
Output Diode Current	$I_{OK}$	$\pm 50$	mA
DC Output Current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /Ground Current	$I_{CC}$	$\pm 100$	mA
Power Dissipation	$P_D$	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	$T_{stg}$	-65~150	°C

\*500mW in the range of  $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$ . From  $T_a = 65^{\circ}\text{C}$  to  $85^{\circ}\text{C}$  a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  should be applied up to 300mW.

**RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	$V_{CC}$	2.0~5.5	V
Input Voltage	$V_{IN}$	0~ $V_{CC}$	V
Output Voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise and Fall Time	$dt/dV$	0~ 100 ( $V_{CC} = 3.3 \pm 0.3\text{V}$ ) 0~ 20 ( $V_{CC} = 5 \pm 0.5\text{V}$ )	ns/V

**DC ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	Ta = 25°C			Ta = -40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	$V_{IH}$		2.0 3.0 5.5	1.50 2.10 3.85	— — —	— — —	1.50 2.10 3.85	— — —	V
Low - Level Input Voltage	$V_{IL}$		2.0 3.0 5.5	— — —	— — —	0.50 0.90 1.65	— — —	0.50 0.90 1.65	V
High - Level Output Voltage	$V_{OH}$	$V_{IN} = V_{IH}$	$I_{OH} = -50\mu\text{A}$	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	— — —
			$I_{OH} = -4\text{mA}$	3.0 4.5	2.58 3.94	— —	— —	2.48 3.80	— —
			$I_{OH} = -24\text{mA}$	—	—	—	—	3.85	—
			$I_{OH} = -75\text{mA}^*$	5.5	—	—	—	—	—
Low - Level Output Voltage	$V_{OL}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50\mu\text{A}$	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	— — —	0.1 0.1 0.1
			$I_{OL} = 12\text{mA}$	3.0 4.5	— —	— —	0.36 0.36	— —	0.44 0.44
			$I_{OL} = 24\text{mA}$	5.5	—	—	—	—	1.65
			$I_{OL} = 75\text{mA}^*$	—	—	—	—	—	—
Input Leakage Current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu\text{A}$
Quiescent Supply Current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	

\* : This spec indicates the capability of driving  $50\Omega$  transmission lines.

One output should be tested at a time for a 10ms maximum duration.

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50\text{pF}$ ,  $R_L = 500\Omega$ , Input  $t_r = t_f = 3\text{ns}$ )

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C		UNIT
			V <sub>CC</sub> (V)	MIN.	TYP.	MAX.	MIN.	
Propagation Delay Time	$t_{PLH}$ $t_{PHL}$		$3.3 \pm 0.3$ $5.0 \pm 0.5$	—	8.0 6.0	14.0 9.0	1.0 1.0	16.0 10.2
Input Capacitance	C <sub>IN</sub>		—	5	10	—	10	—
Power Dissipation Capacitance	C <sub>PD(1)</sub>		—	63	—	—	—	pF

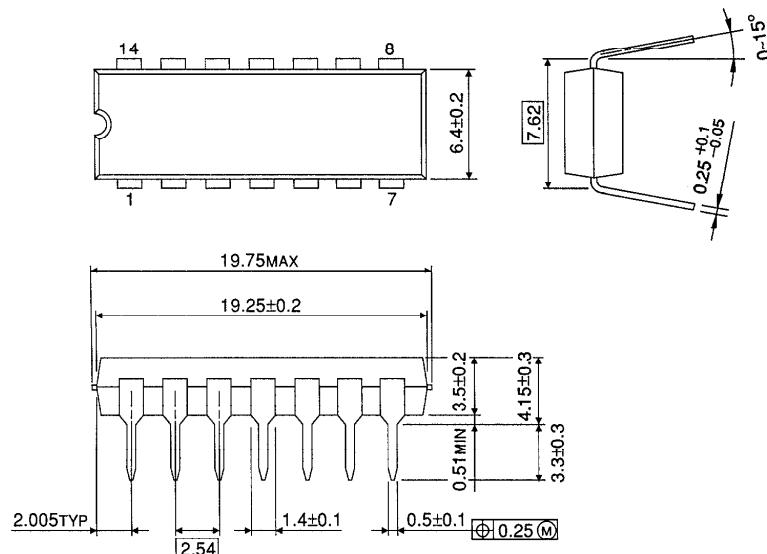
Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3 \text{ (per Gate)}$$

DIP 14PIN OUTLINE DRAWING (DIP14-P-300)

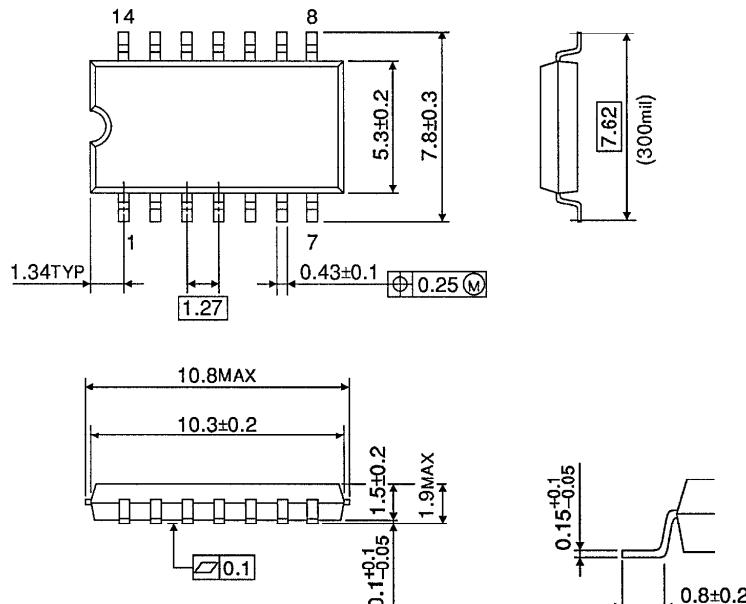
Unit in mm



Weight: 0.96g (TYP.)

SOP 14PIN (200mil BODY) OUTLINE DRAWING (SOP14-P-300)

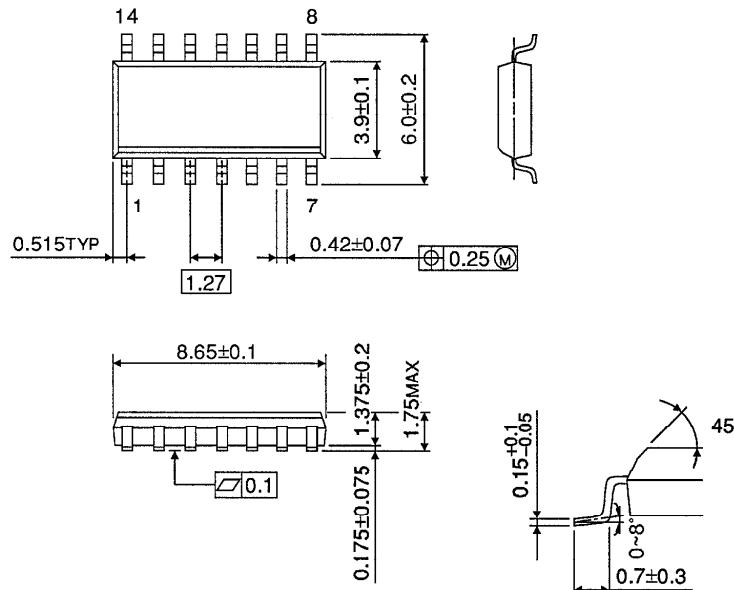
Unit in mm



Weight: 0.18g (TYP.)

SOP 14PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150)

Unit in mm



Weight : 0.12g (TYP.)